DECLARATION FOR PATENT APPLICATION

As the below named inventor(s), I/we hereby declare that:

My residence, post o	office address and citizens	ship are as stated below next to ntor of the subject matter which	my name.
		of Fabricating a MOSFET Devi	
, the specification of which:		of radicating a WOSFET Devi	ce
\bowtie is	s attached hereto.	1 6 . 131	
H w	vas filed on as App	olication Serial No U.S. Express Mail No	
⊢≝	s set forth in PCT Interna	tional Application No;	
fil	led on and as ame	nded Under PCT Article 19 on	(if any).
I/we hereby state that I/we have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.			
I/we acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, §1.56.			
provisional patent applicatio also identified below any Ur inventor's certificate having	on, foreign application(s) nited States provisional p	United States Code, §119 of an for patent or inventor's certificatent application, foreign application the above-identified application.	ate listed below and have cation for patent or
claimed:			
Prior Foreign Application(Priority Claimed
Number 9	Country	Day/Month/Year Filed November 18, 2003	Yes No
92132342 T	ralwan, R.O.C.	November 18, 2003	X
I/we hereby claim the benefit under Title 35, United States Code, §120 of any United States patent			
application(s) listed below and insofar as the subject matter of each of the claims of this application is not			

I/we hereby claim the benefit under Title 35, United States Code, §120 of any United States patent application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, §112, I/we acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, §1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application: **NOT APPLICABLE.**

I/we hereby appoint the following attorneys/agents to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith: George M. Thomas, Reg. No. 22,260; James W. Kayden, Reg. No. 31,532; Scott A. Horstemeyer, Reg. No. 34,183; Stephen R. Risley, Reg. No. 35,659; Jeffrey R. Kuester, Reg. No. 34,367; Daniel R. McClure, Reg. No. 38,962; Daniel J. Santos, Reg. No. 40,158; Dan R. Gresham, Reg. No 41,805; J. Scott Culpepper, Reg. No. 41,692; Michael J. Tempel, Reg. No. 41,344; David R. Risley, Reg. No. 39,345; David L. Berdan, Reg. No. 41,614; Jon E. Holland, Reg. No. 41,077; Ann I. Dennen, Reg. No. 44,651; M. Paul Qualey, Reg. No 43,024; Jennifer M. Gruber, Reg. No. 42,601; Peter A. Nieves, Reg. No. 48,173; William F. Heinze, Reg. No. 36,161; Raymond W. Armentrout, Reg. No. 45,866; Robert A. Blaha, Reg. No. 43,502; Cynthia J. Lee, Reg. No. 46,033; N. Andrew Crain, Reg. No. 45,442; Robert B. Dulaney III, Reg. No. 47,539; Christopher B. Linder, Ph.D., Reg. No. 47,751; Adam E. Crall, Reg. No. 46,646; Edwina T. Washington; Reg. No. 43,187; Scott M. Lohnes, Reg. No. 45,451; Sami O. Malas, Reg. No. 44,893; David Rodack, Reg. 47,034; Troy VanAacken, Reg. No. 50,847; Charles W. Griggers, Reg. No. 47,283; Robert E. Stachler II, Reg. No. 36,934; David P. Kelley, Reg. No. 17,420; Eric M. Ringer, Reg. No. 47,028; Charles E. Thorpe, Jr., Reg. No. 48,782; Harold L. Marquis, Reg. No. 20,594; Sam Han, Reg. No. P51,771; Kenneth C. Brulev, Reg. No. P51,504; Glenn W. Brown, Reg. No. 51,310; and Curtis W. Dodd, Reg. No. 37,314.

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I/we hereby declare that all statements made herein of my/our own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statement and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

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